

Technical Data Data Sheet N1088, Rev. - **Green Products**

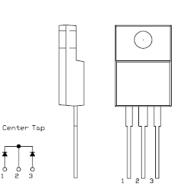
MURF1630CT ULTRAFAST PLASTIC RECTIFIER

Applications:

- **Switching Power Supply**
- **Power Switching Circuits**
- **General Purpose**

Features:

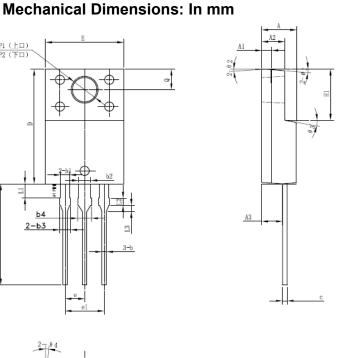
- **Ultra-Fast Switching**
- **High Current Capability**
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



OUTLINE DRAWING

<u>ΦP1(上口)</u> ΦP2(下口) ٦. b4 2-ь3

2<u>-</u>__θ 4



SYMBOL	MIN.	TYP.	MAX.	
A	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80 2.50	3.00	3.20 2.90 0.75	
A3	2.50	3.00 2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.20 1.60	1.35 1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
c D	0.55	0.60	0.75 15.20	
D	14.80	15.00	15.20	
E	9.96	10.16 2.55	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	<u>12.70</u> 1.60	13.20	13.70 2.00 1.20	
L1	1.60	1.80 1.00	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦΡ1(上口)	3.30 2.99	3.50	3.70	
ΦΡ2 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°	l°	
Θ3		10°		
Θ4		5°		
Θ5		5°		

ITO-220AB

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Where XXXXX is YYWWL

= Device Type

= Package type

= Configuration

= Lot Number

= SSG

= Year

= Week

= Forward Current (16A)

= Reverse Voltage (300V)

MUR

F

16

30

CT SSG

YΥ

L

WW

Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MURF1630CT	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



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Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MURF1630CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	300	V
Average Rectified Output Current @ $T_A = 55^{\circ}C$	lo	16.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	130	A
Forward Voltage (per element) $@I_F = 8.0A, T_J=25^{\circ}C$	V _{FM1}	1.55	V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 125^{\circ}C$	I _R	5 500	μA
Maximum Reverse Recovery Time (Note 1)	Trr	35	ns
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C
Approximate Weight	wt	2.0	g
Case Style	ITO-220AB		

Note: 1.Measured with I_F =0.5A; I_R =1.0A; I_{RR} =0.25A.

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